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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/609,813	07/03/2000	Leonard Forbes	M4065.0051/P051-A	4281

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EXAMINER

BROCK II, PAUL E

ART UNIT	PAPER NUMBER
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2815

DATE MAILED: 01/09/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

**Office Action Summary**

Application No.

09/609,813

Applicant(s)

FORBES ET AL.

Examiner

Paul E Brock II

Art Unit

2815

-- The MAILING DATE of this communication appears on the cover sheet with the corresponding address --

**Period for Reply**

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

**Status**

- 1) ☒ Responsive to communication(s) filed on 11 December 2001.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

**Disposition of Claims**

- 4) ☒ Claim(s) 48-61 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 48-61 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

**Application Papers**

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☒ The drawing(s) filed on 03 July 2000 is/are: a) ☒ accepted or b) ☐ objected to by the Examiner.
- Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) ☐ The proposed drawing correction filed on \_\_\_\_\_ is: a) ☐ approved b) ☐ disapproved by the Examiner.
- If approved, corrected drawings are required in reply to this Office action.
- 12) ☐ The oath or declaration is objected to by the Examiner.

**Priority under 35 U.S.C. §§ 119 and 120**

- 13) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some \* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
- \* See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).
- a) ☐ The translation of the foreign language provisional application has been received.
- 15) ☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

**Attachment(s)**

- 1) ☒ Notice of References Cited (PTO-892)
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449) Paper No(s) \_\_\_\_\_
- 4) ☐ Interview Summary (PTO-413) Paper No(s). \_\_\_\_\_
- 5) ☐ Notice of Informal Patent Application (PTO-152)
- 6) ☐ Other:

## DETAILED ACTION

### *Claim Rejections - 35 USC § 103*

1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

2. Claims 48 – 61 are rejected under 35 U.S.C. 103(a) as being unpatentable over Ueno (USPAT 5346838, Ueno) in view of Bhagat (USPAT 4861731).

Ueno discloses in figure 3 a method of forming a circuit for storing information as one of at least two possible stable current states in figures 3 – 6.

With regard to claim 48 and 55, Ueno discloses in figure 3 providing a semiconductor substrate (11). Ueno discloses in figure 3 providing doped silicon regions to form a multi-region planar thyristor having at least four regions. Ueno discloses in figure 3 forming at least one polysilicon gate (20) overlying a junction of the multi-region planar thyristor thereby making the junction a gated diode. Ueno discloses in figures 3 and 4 connecting the at least one polysilicon gate to a voltage source (G) in the multi-region planar thyristor. It is inherent that the voltage source is for producing latch-up in the multi-region planar thyristor. Ueno does not disclose that the junction is defined only by a single junction. Bhagat teaches in figure 1 forming at least one gate (54) overlying a single junction (the junction between regions 36 and 45). It would have been obvious to one of ordinary skill in the art at the time of the present invention to use the gate

overlying a single junction in the method of Ueno in order to turn the thyristor off as stated by Bhagat in column 6, lines 15 – 18.

With regard to claim 49 and 56, Ueno discloses in figure 3 providing doped silicon regions that form a seven region planar thyristor.

With regard to claim 50 and 57, Ueno discloses in figure 3 providing doped silicon regions that form a p-n-p-n-p-n-p planar thyristor.

With regard to claim 52 and 59, Ueno discloses in figure 4 the step of providing doped silicon regions further comprises forming two memory cells (CH0 and CH1)

With regard to claim 53 and 60, Ueno discloses in figures 3 and 4 connecting a central region of the seven-region planar thyristor to a shared row address line (C).

With regard to claim 54 and 61, Ueno discloses in figure 4 the step of providing doped silicon regions further comprises forming one memory cell (CH0).

With regard to claims 51 and 58, Ueno discloses a p-n-p-n-p-n-p planar thyristor. Ueno and Bhagat do not disclose an n-p-n-p-n-p-n planar thyristor. It is well known in the art to form semiconductor devices of reverse polarity. It would have been obvious to one of ordinary skill in the art at the time of the present invention to form an n-p-n-p-n-p-n planar thyristor in the method of Ueno and Bhagat for design choice of the manufacturer.

### ***Response to Arguments***

3. Applicant's arguments with respect to claims 48 – 54 have been considered but are moot in view of the new ground(s) of rejection.

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***Conclusion***

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Paul E Brock II whose telephone number is (703)308-6236. The examiner can normally be reached on 8:30 AM-5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on (703)308-1690. The fax phone numbers for the organization where this application or proceeding is assigned are (703)308-7722 for regular communications and (703)308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703)308-0956.

Paul E Brock II  
December 28, 2001



**EDDIE LEE**  
**SUPERVISORY PATENT EXAMINER**  
**TECHNOLOGY CENTER 2800**